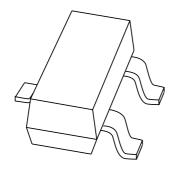
### DISCRETE SEMICONDUCTORS

## DATA SHEET



# **BF840**NPN medium frequency transistor

Product specification
Supersedes data of 1998 Dec 02

1999 Apr 12





## NPN medium frequency transistor

**BF840** 

#### **FEATURES**

- Low current (max. 25 mA)
- Low voltage (max. 40 V).

#### **APPLICATIONS**

- AM mixers
- IF amplifiers in AM/FM receivers.

#### **DESCRIPTION**

NPN medium frequency transistor in a SOT23 plastic package.

#### **MARKING**

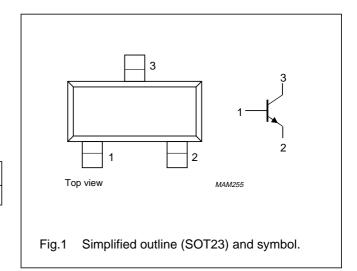
TYPE NUMBER	MARKING CODE(1)
BF840	NC*

#### Note

\* = p : Made in Hong Kong.
 \* = t : Made in Malaysia.

#### **PINNING**

PIN	DESCRIPTION
1	base
2	emitter
3	collector



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	40	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	40	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	4	V
I <sub>C</sub>	collector current (DC)		_	25	mA
I <sub>CM</sub>	peak collector current		_	25	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

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#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V	_	_	100	nA
I <sub>EBO</sub>	emitter cut-off current	$I_C = 0; V_{EB} = 4 V$	_	_	100	nA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 1 mA; V <sub>CE</sub> = 10 V	67	_	222	
$V_{BE}$	base-emitter voltage	$I_C = 1 \text{ mA}; V_{CE} = 10 \text{ V}$	675	725	775	mV
C <sub>re</sub>	feedback capacitance	I <sub>C</sub> = 0; V <sub>CB</sub> = 10 V; f = 1 MHz	_	0.3	_	pF
f <sub>T</sub>	transition frequency	$I_C = 1 \text{ mA}; V_{CE} = 10 \text{ V}; f = 100 \text{ MHz}$	_	380	_	MHz

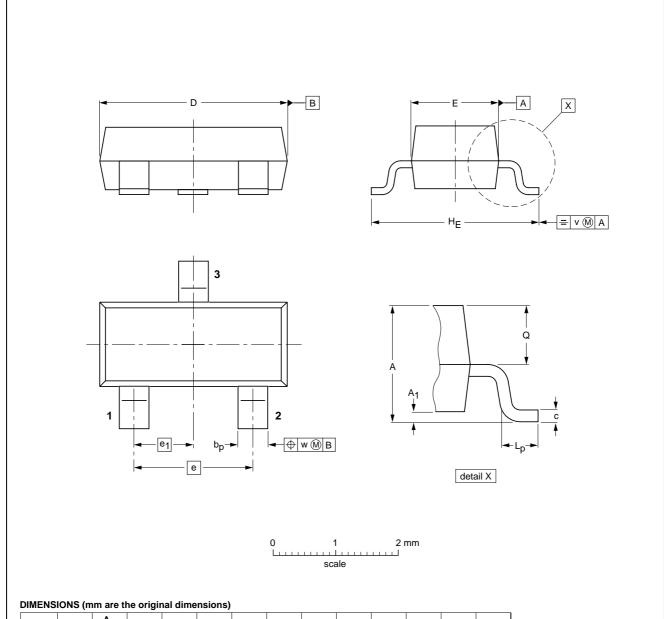
## NPN medium frequency transistor

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#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

SOT23



UNIT	Α	A <sub>1</sub> max.	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	٧	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT23					97-02-28

Product specification Philips Semiconductors

#### NPN medium frequency transistor

**BF840** 

#### **DEFINITIONS**

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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## NPN medium frequency transistor

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NOTES

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## NPN medium frequency transistor

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NOTES

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